

2GHz image rejecting front-end

UAA2077BM

FEATURES

- Low-noise, wide dynamic range amplifier
- Very low noise figure
- Dual balanced mixer for over 25 dB on-chip image rejection
- IF I/Q combiner at 188 MHz
- On-chip quadrature network
- Down-conversion mixer for closed-loop transmitters
- Independent TX/RX fast ON/OFF power-down modes
- Very small outline packaging
- Very small application (no image filter).

APPLICATIONS

- 1800 MHz front-end for DCS1800 hand-portable equipment
- Compact digital mobile communication equipment
- TDMA receivers e.g. PCS, RF-LANS.

GENERAL DESCRIPTION

UAA2077BM contains both a receiver front-end and a high frequency transmit mixer intended to be used in mobile telephones. Designed in an advanced BiCMOS process it combines high performance with low power consumption and a high degree of integration, thus reducing external component costs and total front-end size.

The main advantage of the UAA2077BM is its ability to provide over 25 dB of image rejection. Consequently, the image filter between the LNA and the mixer is suppressed.

Image rejection is achieved in the internal architecture by two RF mixers in quadrature and two all-pass filters in I and Q IF channels that phase shift the IF by 45° and 135° respectively. The two phase shifted IFs are recombined and buffered to furnish the IF output signal.

For instance, signals presented at the RF input at LO + IF frequency are rejected through this signal processing while signals at LO – IF frequency can form the IF signal. An internal switch allows the use of infradyne (LO < RF) or supradyn (LO > RF) reception.

The receiver section consists of a low-noise amplifier that drives a quadrature mixer pair. The IF amplifier has on-chip 45° and 135° phase shifting and a combining network for image rejection. The IF driver has differential open-collector type outputs.

The LO part consists of an internal all-pass type phase shifter to provide quadrature LO signals to the receive mixers. The centre frequency of the phase shifter is adjustable for maximum image rejection in a given band. The all-pass filters outputs are buffered before being fed to the receive mixers.

The transmit section consists of a low-noise amplifier, and a down-conversion mixer. In the transmit mode an internal LO buffer is used to drive the transmit IF down-conversion mixer.

All RF and IF inputs or outputs are balanced.

Pins RXON, TXON and SXON allow a selection of whether to reject the upper or lower image frequency and control of the different power-down modes. Special care has been taken for fast power-up switching.

QUICK REFERENCE DATA

| SYMBOL | PARAMETER | MIN. | TYP. | MAX. | UNIT |
|------------------------------|-------------------------------|------|------|------|------|
| V _{CC} | supply voltage | 3.6 | 4.0 | 5.3 | V |
| I _{CCR_X} | receive supply current | 22 | 27 | 33 | mA |
| I _{CCT_X} | transmit supply current | 11 | 14 | 17 | mA |
| I _{CCPD} | supply current in power-down | – | – | 50 | µA |
| T _{amb} | operating ambient temperature | –30 | +25 | +85 | °C |

ORDERING INFORMATION

| TYPE NUMBER | PACKAGE | | |
|-------------|---------|---|----------|
| | NAME | DESCRIPTION | VERSION |
| UAA2077BM | SSOP20 | plastic shrink small outline package; 20 leads; body width 4.4 mm | SOT266-1 |

2GHz image rejecting front-end

UAA2077BM

BLOCK DIAGRAM

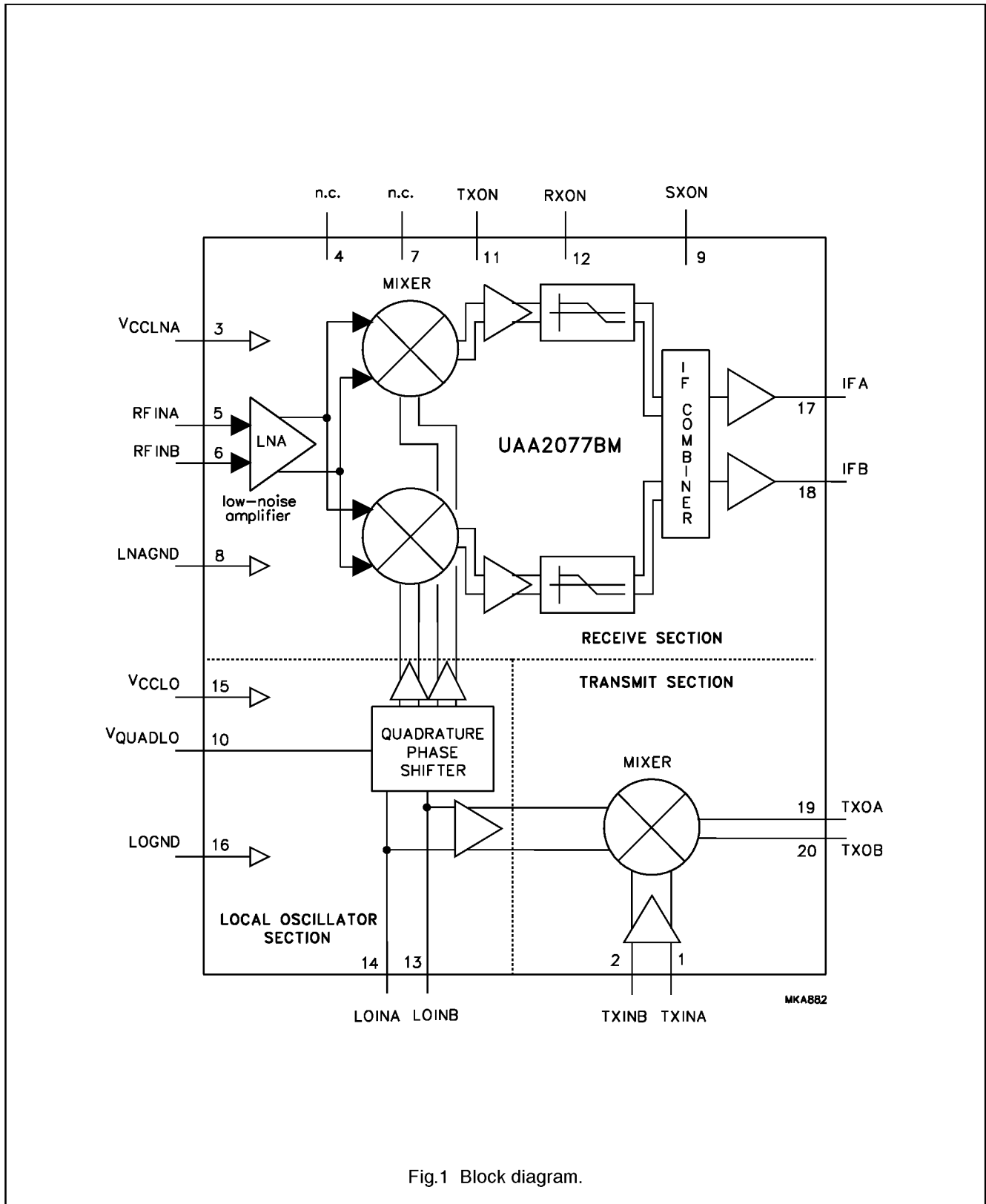


Fig.1 Block diagram.

2GHz image rejecting front-end

UAA2077BM

PINNING

| SYMBOL | PIN | DESCRIPTION |
|---------------------|-----|---|
| TXINA | 1 | transmit mixer input A (balanced) |
| TXINB | 2 | transmit mixer input B (balanced) |
| V _{CCLNA} | 3 | supply voltage for LNA, IF parts and TX mixer |
| n.c. | 4 | not connected |
| RFINA | 5 | RF input A (balanced) |
| RFINB | 6 | RF input B (balanced) |
| n.c. | 7 | not connected |
| LNAGND | 8 | ground for LNA and IF parts |
| SXON | 9 | synthesizer-ON mode enable |
| V _{QUADLO} | 10 | input voltage for LO quadrature trimming |
| TXON | 11 | transmit mode enable |
| RXON | 12 | receive mode enable |
| LOINB | 13 | LO input B (balanced) |
| LOINA | 14 | LO input A (balanced) |
| V _{CCLLO} | 15 | supply voltage for LO parts |
| LOGND | 16 | ground for LO parts |
| IFA | 17 | IF output A (balanced) |
| IFB | 18 | IF output B (balanced) |
| TXOA | 19 | transmit mixer IF output A (balanced) |
| TXOB | 20 | transmit mixer IF output B (balanced) |

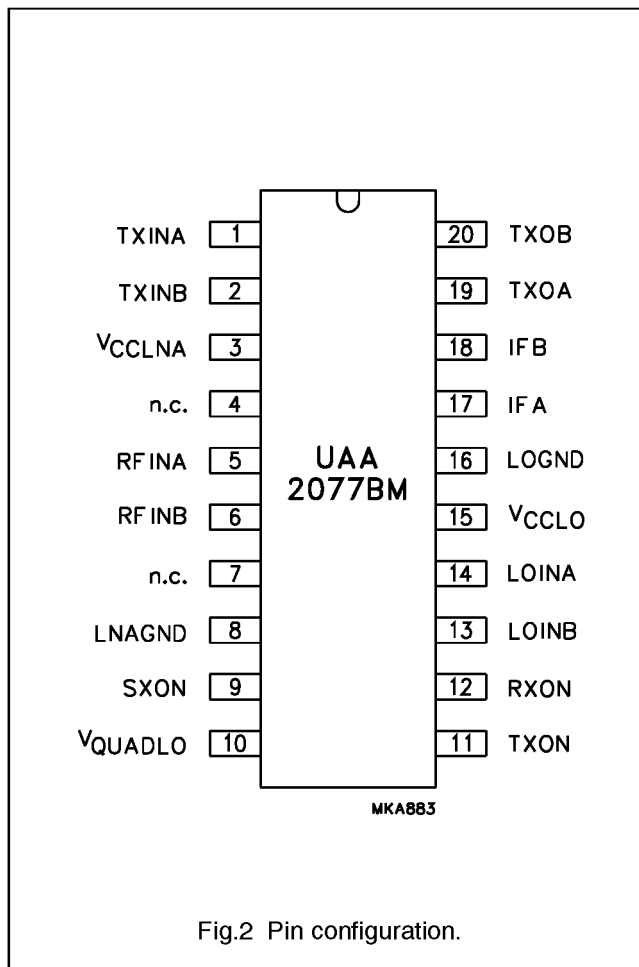


Fig.2 Pin configuration.

2GHz image rejecting front-end

UAA2077BM

FUNCTIONAL DESCRIPTION

Receive section

The circuit contains a low-noise amplifier followed by two high dynamic range mixers. These mixers are of the Gilbert-cell type, the whole internal architecture is fully differential.

The local oscillator, shifted in phase to 45° and 135°, mixes the amplified RF to create I and Q channels. The two I and Q channels are buffered, phase shifted by 45° and 135° respectively, amplified and recombined internally to realize the image rejection.

Balanced signal interfaces are used for minimizing crosstalk due to package parasitics. The RF differential input impedance is 35 Ω (real part).

The IF output is differential and of the open-collector type. Typical application will load the output with a differential 1 kΩ load; i.e. a 1 kΩ resistor load at each IF output, plus a 2 kΩ to x Ω narrow band matching network (x Ω being the input impedance of the IF filter). The path to V_{CC} for the DC current is achieved via tuning inductors. The output voltage is limited to V_{CC} + 3V_{be} or 3 diode forward voltage drops.

Fast switching, ON/OFF, of the receive section is controlled by the hardware input RXON.

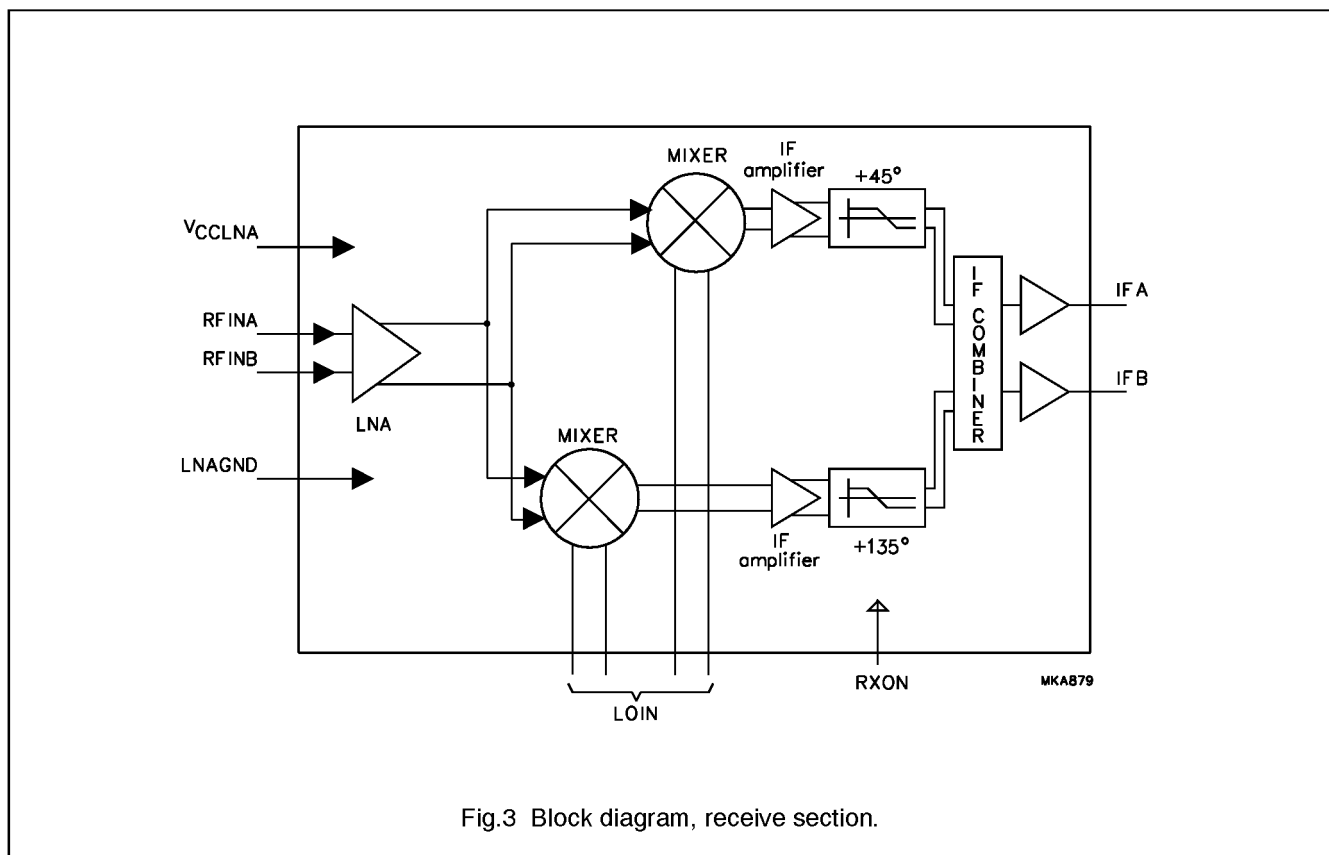


Fig.3 Block diagram, receive section.

2GHz image rejecting front-end

UAA2077BM

Local oscillator section

The local oscillator (LO) input directly drives the two internal all-pass networks to provide quadrature LO to the receive mixers.

The centre frequency of the receive band is adjustable by the voltage on pin V_{QUADLO} . This should be done by connecting a resistor between V_{QUADLO} and V_{CC} . Over 25 dB of image rejection can be obtained by an optimum resistor value.

The LO differential input impedance is $35\ \Omega$ (real part). A synthesizer-ON mode is used to power-up all LO input buffers, thus minimizing the pulling effect on the external VCO when entering receive or transmit mode. This mode is active when $SXON = 1$.

Transmit mixer

This mixer is used for down-conversion to the transmit IF. Its inputs are coupled to the transmit RF which is down-converted to a modulated transmit IF frequency, phase locked with the baseband modulation.

The transmit mixer provides a differential input at $40\ \Omega$ and a differential HIGH impedance output. The IF outputs are HIGH impedance (open-collector type); i.e. a $500\ \Omega$ resistor load at each IF output, plus a $1\ k\Omega$ to $x\ \Omega$ narrow band matching network ($x\ \Omega$ being the input impedance of the IF filter). The mixer can also be used for frequency up-conversion.

Fast switching, ON/OFF, of the transmit section is controlled by the hardware input TXON.

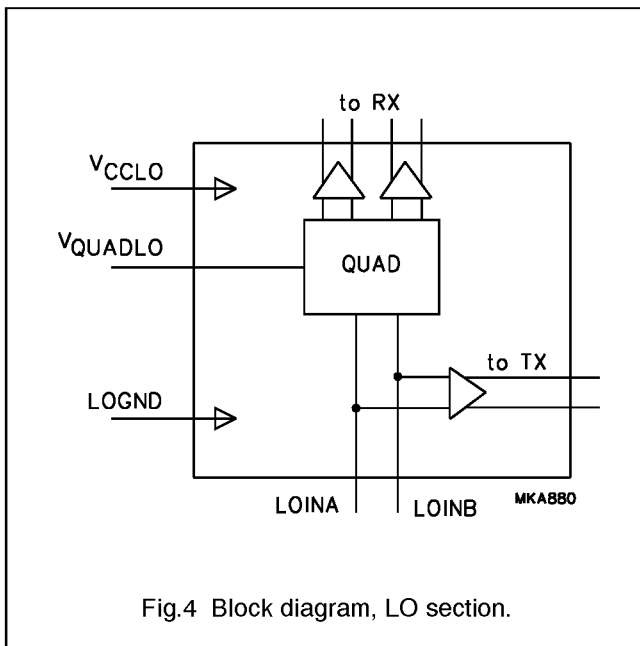


Fig.4 Block diagram, LO section.

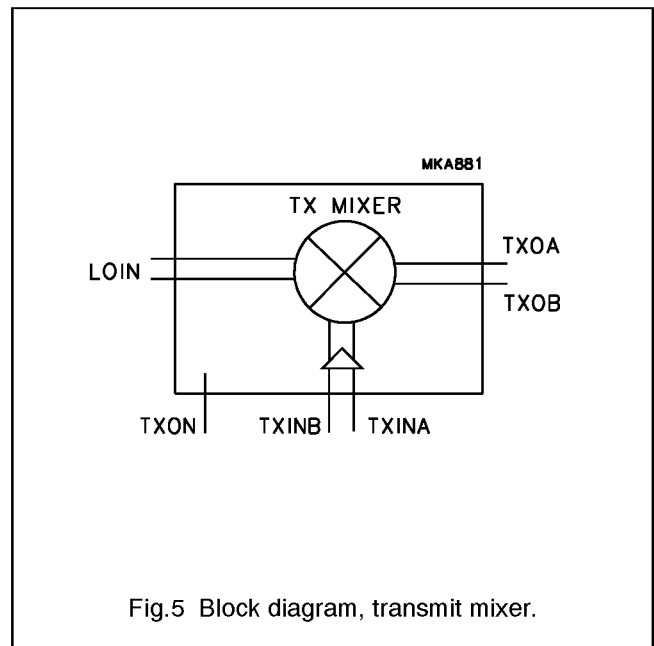


Fig.5 Block diagram, transmit mixer.

Table 1 Control of power status

| EXTERNAL PIN LEVEL | | | CIRCUIT MODE OF OPERATION |
|--------------------|------|------|--|
| TXON | RXON | SXON | |
| LOW | LOW | LOW | power-down mode |
| LOW | HIGH | LOW | receive section on, infradyne reception |
| HIGH | LOW | LOW | transmit section on |
| LOW | LOW | HIGH | synthesizer-ON mode (only LO buffers enabled) |
| LOW | HIGH | HIGH | receive section on and synthesizer-ON mode active, infradyne reception |
| HIGH | LOW | HIGH | transmit section on and synthesizer-ON mode active |
| HIGH | HIGH | LOW | receive section on, supradyn reception |
| HIGH | HIGH | HIGH | receive section on and synthesizer-ON mode active, supradyn reception |

2GHz image rejecting front-end

UAA2077BM

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL | PARAMETER | MIN. | MAX. | UNIT |
|----------------|--|------|------|------|
| V_{CC} | supply voltage | – | 9 | V |
| ΔGND | difference in ground supply voltage applied between LOGND and LNAGND | – | 0.6 | V |
| $P_{I(max)}$ | maximum power input | – | +20 | dBm |
| $T_{j(max)}$ | maximum operating junction temperature | – | +150 | °C |
| $P_{dis(max)}$ | maximum power dissipation in quiet air | – | 250 | mW |
| T_{stg} | storage temperature | –65 | +150 | °C |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | VALUE | UNIT |
|---------------|---|-------|------|
| $R_{th\ j-a}$ | thermal resistance from junction to ambient in free air | 120 | K/W |

HANDLING

Every pin withstands 1500 V ESD Human Model and 200 V Machine Model; refer to MIL-STD-883C class 2 (method 3015.5).

2GHz image rejecting front-end

UAA2077BM

DC CHARACTERISTICS

$V_{CC} = 4\text{ V}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$; unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--|-----------------------------------|---|-------------|------|----------|---------------|
| Pins: $V_{CC(LNA)}$, $V_{CC(LO)}$ | | | | | | |
| V_{CC} | supply voltage | over full temperature range | 3.6 | 4.0 | 5.3 | V |
| $I_{CC(RX)}$ | supply current | receive mode active; DC tested | 22 | 27 | 33 | mA |
| $I_{CC(TX)}$ | supply current | transmit mode active; DC tested | 11 | 14 | 17 | mA |
| $I_{CC(PD)}$ | supply current in power-down mode | DC tested | – | – | 50 | μA |
| $I_{CC(SX)}$ | supply current | synthesizer-ON mode only | 6 | 7.5 | 9 | mA |
| $I_{CC(SRX)}$ | supply current | receive and synthesizer-ON mode active | – | 29 | – | mA |
| $I_{CC(STX)}$ | supply current | transmit and synthesizer-ON mode active | – | 18 | – | mA |
| Pins: RXON, TXON and SXON | | | | | | |
| V_{th} | CMOS threshold voltage | note 1 | – | 1.25 | – | V |
| V_{IH} | HIGH level input voltage | | $0.7V_{CC}$ | – | V_{CC} | V |
| V_{IL} | LOW level input voltage | | –0.3 | – | 0.8 | V |
| I_{IH} | HIGH level static input current | pins at $V_{CC} - 0.4\text{ V}$ | –1 | – | +1 | μA |
| I_{IL} | LOW level static input current | pins at 0.4 V | –1 | – | +1 | μA |
| Pins: RFINA and RFINB | | | | | | |
| V_I | DC input voltage level | receive mode enabled | – | 2.0 | – | V |
| Pins: IFA and IFB | | | | | | |
| I_O | DC output current | receive mode enabled | – | 2.5 | – | mA |
| Pins: TXINA and TXINB | | | | | | |
| V_I | DC input voltage level | transmit section enabled | – | 2.0 | – | V |
| Pins: TXOA and TXOB | | | | | | |
| I_O | DC output current | transmit section enabled | – | 0.9 | – | mA |
| Pins: LOINA and LOINB | | | | | | |
| V_{LOIN} | DC input voltage level | RXON, TXON or SXON HIGH | – | 3.3 | – | V |

Note

1. The referenced inputs should be connected to a valid CMOS input level.

2GHz image rejecting front-end

UAA2077BM

AC CHARACTERISTICS

$V_{CC} = 4\text{ V}$; $T_{amb} = -30\text{ to }+85\text{ }^{\circ}\text{C}$; unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--|--|--|------|------|------|------------|
| Receive section (receive section enabled) | | | | | | |
| Z_{RFI} | RF input impedance (real part) | balanced; at 1850 MHz | – | 35 | – | Ω |
| f_{RFI} | RF input frequency | | 1800 | – | 2000 | MHz |
| RL_{RF} | return loss on matched RF input | balanced; note 1 | 11 | 15 | – | dB |
| G_{CP} | conversion power gain | differential RF inputs to differential IF outputs loaded to 1 k Ω differential | 17 | 20 | 23 | dB |
| G_{rip} | gain ripple as a function of RF frequency | between 1805 and 1880 MHz; note 2 | – | 0.1 | – | dB |
| $\Delta G/T$ | gain variation with temperature | note 2 | –15 | –10 | –5 | mdB/K |
| $CP1_{RX}$ | 1 dB compression point | differential RF inputs to differential IF outputs; note 1 | –26 | –23 | – | dBm |
| DES3 | 3 dB desensitisation point | interferer frequency offset: 3 MHz; differential RF inputs to differential IF outputs; note 1 | – | –30 | – | dBm |
| | | interferer frequency offset: 20 MHz; differential RF inputs to differential IF outputs; note 1 | – | –27 | – | dBm |
| $IP2D_{RX}$ | 2nd order intercept point | differential RF inputs to differential IF outputs; note 2 | +15 | +22 | – | dBm |
| $IP3_{RX}$ | 3rd order intercept point | differential RF inputs to differential IF outputs; note 2 | –23 | –17 | – | dBm |
| NF_{RX} | overall noise figure | differential RF inputs to differential IF outputs; notes 2 and 3 | – | 4.3 | 5.0 | dB |
| $Z_{L(IF)}$ | typical application IF output load impedance | balanced | – | 1 | – | k Ω |
| RL_{IF} | return loss on matched IF input | balanced; note 1 | 11 | 15 | – | dB |
| f_{IF} | IF frequency range | | 170 | 188 | 210 | MHz |
| IR | rejection of image frequency | V_{QUADLO} tuned | 20 | – | – | dB |
| | | infradyne; $f_{IF} = 188\text{ MHz}$; note 4 | 25 | 32 | – | dB |

2GHz image rejecting front-end

UAA2077BM

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---|---|--|------|------|------|----------|
| Local oscillator section (receive section enabled) | | | | | | |
| f_{LO} | LO input frequency | | 1600 | – | 2200 | MHz |
| Z_{LO} | LO input impedance (real part) | balanced | – | 35 | – | Ω |
| RL_{LO} | return loss on matched input (including standby mode) | note 1 | 9 | 12 | – | dB |
| ΔRL_{LO} | return loss variation between SX, SRX and STX modes | linear S_{11} variation; note 1 | – | | – | mU |
| $P_{i(LO)}$ | LO input power level | | –6 | –3 | +3 | dBm |
| RI_{LO} | reverse isolation | LOIN to RFIN at LO frequency; note 1 | 40 | – | – | dB |
| R_{tune} | image rejection tuning resistor | connected between V_{QUADLO} and V_{CC} | 0 | 1000 | – | Ω |
| Transmit section (transmit section enabled) | | | | | | |
| Z_L | TX IF typical load impedance | | – | 500 | – | Ω |
| RL_{TXIF} | return loss on matched transmitter IF input | | 11 | 15 | – | dB |
| $Z_{i(RF)}$ | TX RF input impedance (real part) | balanced; at 1750 MHz | – | 40 | – | Ω |
| f_{TXmix} | TX mixer input frequency | | 1600 | – | 2000 | MHz |
| RL_{TX} | return loss on matched TX input | note 1 | 10 | 15 | – | dB |
| G_{CP} | conversion power gain | differential transmitter inputs to differential transmitter IF outputs loaded with 500 Ω differential | 6 | 9 | 12 | dB |
| $f_{o(TX)}$ | TX mixer output frequency | | 50 | – | 400 | MHz |
| $CP1_{TX}$ | 1 dB input compression point | | –25 | –22 | – | dBm |
| $IP2_{TX}$ | 2nd order intercept point | | – | +22 | – | dBm |
| $IP3_{TX}$ | 3rd order intercept point | | –19 | –16 | – | dBm |
| NF_{TX} | noise figure | double sideband; notes 2 and 3 | – | 6 | 9 | dB |
| I_{TX} | isolation | LOIN to TXIN; note 1 | 40 | – | – | dB |
| RI_{TX} | reverse isolation | TXIN to LOIN; note 1 | 40 | – | – | dB |
| Timing | | | | | | |
| t_{stu} | start-up time of each block | | 1 | 5 | 20 | μ s |

Notes

1. Measured and guaranteed only on UAA2077BM demonstration board at $T_{amb} = +25\text{ }^\circ\text{C}$.
2. Measured and guaranteed only on UAA2077BM demonstration board.
3. This value includes printed-circuit board and balun losses.
4. Measured and guaranteed only on UAA2077BM demonstration board at $T_{amb} = +25\text{ }^\circ\text{C}$, with a 1 k Ω resistor between V_{QUADLO} and V_{CC} .

2GHz image rejecting front-end

UAA2077BM

APPLICATION INFORMATION

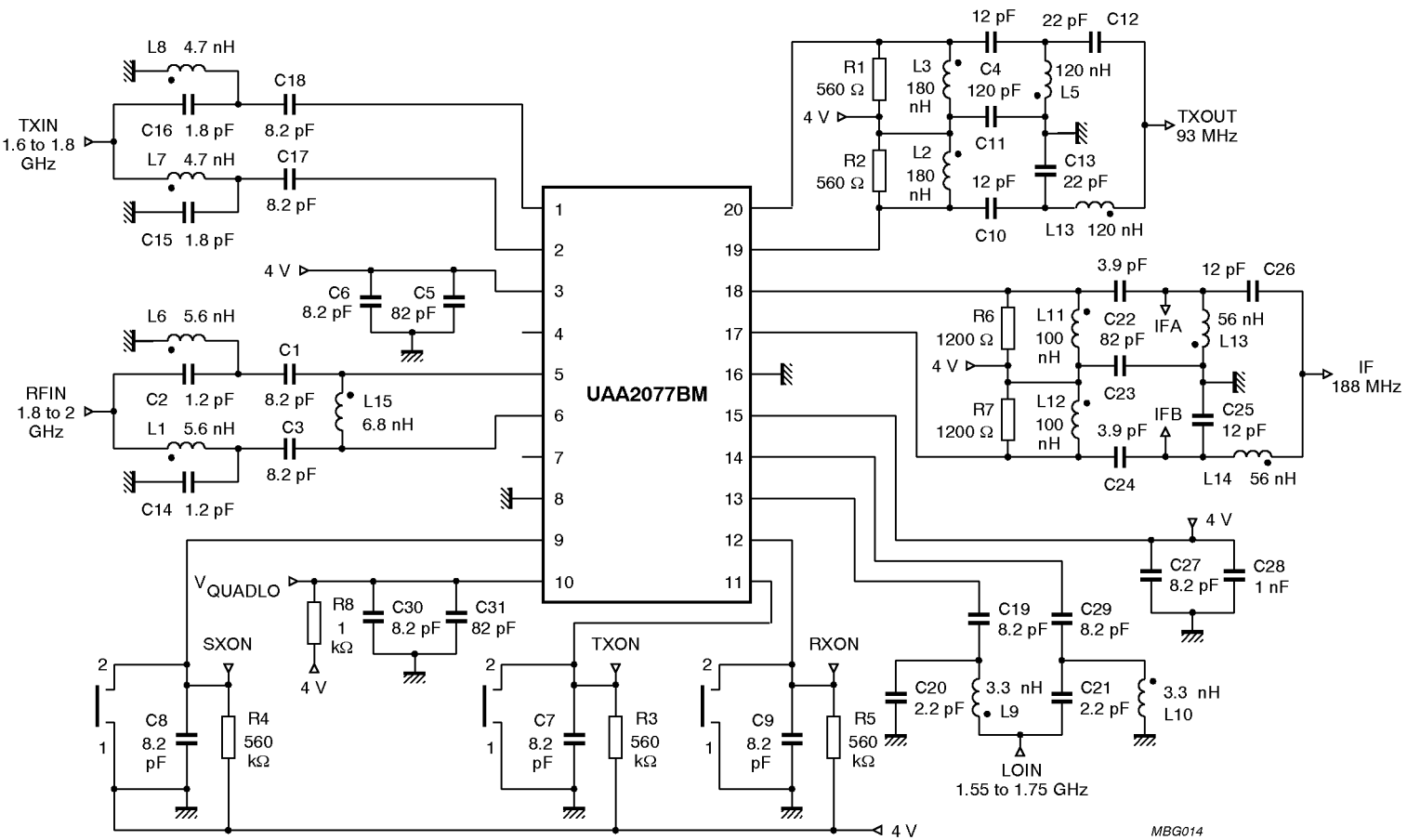


Figure 6 illustrates the electrical diagram of the UAA2077BM Philips demonstration board for DCS1800 applications. For measurement purposes all matching is to 50 Ω. Different values will be used in a real application.

Fig.6 Application diagram.